

# Thyristor

$$V_{RRM} = 1600V$$

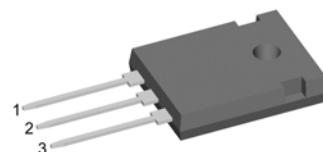
$$I_{TAV} = 40A$$

$$V_T = 1,34V$$

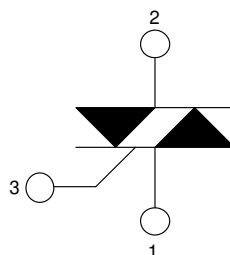
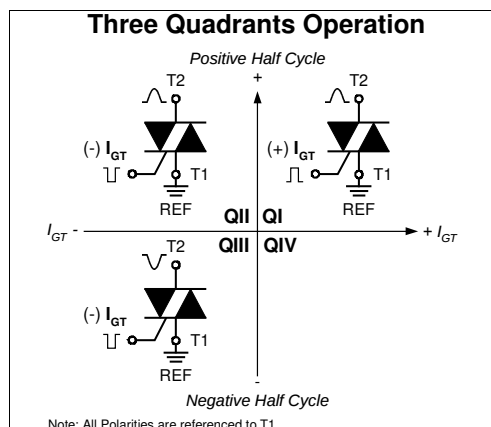
Three Quadrants operation: QI - QIII  
 1~ Triac

Part number

**CMA80MT1600NHB**



Backside: Terminal 2



## Features / Advantages:

- Triac for line frequency
- Three Quadrants Operation
  - QI - QIII
- Planar passivated chip
- Long-term stability of blocking currents and voltages

## Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

## Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

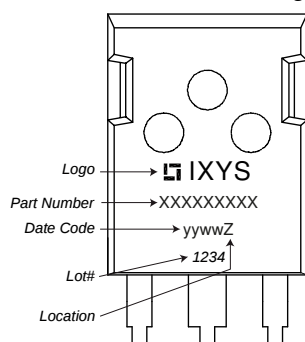
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| Rectifier      |                                                      |                                                                                                                                                                                                       |                                | Ratings |      |          |                  |
|----------------|------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------|---------|------|----------|------------------|
| Symbol         | Definition                                           | Conditions                                                                                                                                                                                            |                                | min.    | typ. | max.     | Unit             |
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                                                         |                                |         |      | 1700     | V                |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                                                                                                                                                         |                                |         |      | 1600     | V                |
| $I_{R/D}$      | reverse current, drain current                       | $V_{R/D} = 1600\text{ V}$                                                                                                                                                                             | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 10       | $\mu\text{A}$    |
|                |                                                      | $V_{R/D} = 1600\text{ V}$                                                                                                                                                                             | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 2        | mA               |
| $V_T$          | forward voltage drop                                 | $I_T = 40\text{ A}$                                                                                                                                                                                   | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1,36     | V                |
|                |                                                      | $I_T = 80\text{ A}$                                                                                                                                                                                   |                                |         |      | 1,70     | V                |
|                |                                                      | $I_T = 40\text{ A}$                                                                                                                                                                                   | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 1,34     | V                |
|                |                                                      | $I_T = 80\text{ A}$                                                                                                                                                                                   |                                |         |      | 1,78     | V                |
| $I_{TAV}$      | average forward current                              | $T_C = 115^{\circ}\text{C}$                                                                                                                                                                           | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 40       | A                |
| $I_{RMS}$      | RMS forward current per phase                        | 180° sine                                                                                                                                                                                             |                                |         |      | 88       | A                |
| $V_{T0}$       | threshold voltage                                    | } for power loss calculation only                                                                                                                                                                     | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 0,89     | V                |
| $r_T$          | slope resistance                                     |                                                                                                                                                                                                       |                                |         |      | 11,3     | m $\Omega$       |
| $R_{thJC}$     | thermal resistance junction to case                  |                                                                                                                                                                                                       |                                |         |      | 0,4      | K/W              |
| $R_{thCH}$     | thermal resistance case to heatsink                  |                                                                                                                                                                                                       |                                |         | 0,25 |          | K/W              |
| $P_{tot}$      | total power dissipation                              |                                                                                                                                                                                                       | $T_C = 25^{\circ}\text{C}$     |         |      | 310      | W                |
| $I_{TSM}$      | max. forward surge current                           | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                                                      | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 380      | A                |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                                                     | $V_R = 0\text{ V}$             |         |      | 410      | A                |
|                |                                                      | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                                                      | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 325      | A                |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                                                     | $V_R = 0\text{ V}$             |         |      | 350      | A                |
| $I^2t$         | value for fusing                                     | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                                                      | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 720      | A <sup>2</sup> s |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                                                     | $V_R = 0\text{ V}$             |         |      | 700      | A <sup>2</sup> s |
|                |                                                      | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$                                                                                                                                                      | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 530      | A <sup>2</sup> s |
|                |                                                      | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$                                                                                                                                                     | $V_R = 0\text{ V}$             |         |      | 510      | A <sup>2</sup> s |
| $C_J$          | junction capacitance                                 | $V_R = 400\text{ V}$ $f = 1\text{ MHz}$                                                                                                                                                               | $T_{VJ} = 25^{\circ}\text{C}$  |         | 14   |          | pF               |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30\text{ }\mu\text{s}$                                                                                                                                                                         | $T_C = 150^{\circ}\text{C}$    |         |      | 10       | W                |
|                |                                                      | $t_p = 300\text{ }\mu\text{s}$                                                                                                                                                                        |                                |         |      | 5        | W                |
| $P_{GAV}$      | average gate power dissipation                       |                                                                                                                                                                                                       |                                |         |      | 0,5      | W                |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 125^{\circ}\text{C}; f = 50\text{ Hz}$ repetitive, $I_T = 90\text{ A}$                                                                                                                      |                                |         |      | 150      | A/ $\mu\text{s}$ |
|                |                                                      | $t_p = 200\text{ }\mu\text{s}; di_G/dt = 0,2\text{ A}/\mu\text{s};$<br>$I_G = 0,2\text{ A}; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 40\text{ A}$                                                |                                |         |      | 500      | A/ $\mu\text{s}$ |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^{\circ}\text{C}$<br>$R_{GK} = \infty$ ; method 1 (linear voltage rise)                                                                                      |                                |         |      | 500      | V/ $\mu\text{s}$ |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6\text{ V}$                                                                                                                                                                                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1,7      | V                |
|                |                                                      |                                                                                                                                                                                                       | $T_{VJ} = -40^{\circ}\text{C}$ |         |      | 1,9      | V                |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6\text{ V}$                                                                                                                                                                                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | $\pm 70$ | mA               |
|                |                                                      |                                                                                                                                                                                                       | $T_{VJ} = -40^{\circ}\text{C}$ |         |      | $\pm 90$ | mA               |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$                                                                                                                                                                           | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 0,2      | V                |
| $I_{GD}$       | gate non-trigger current                             |                                                                                                                                                                                                       |                                |         |      | $\pm 1$  | mA               |
| $I_L$          | latching current                                     | $t_p = 10\text{ }\mu\text{s}$                                                                                                                                                                         | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 100      | mA               |
|                |                                                      | $I_G = 0,2\text{ A}; di_G/dt = 0,2\text{ A}/\mu\text{s}$                                                                                                                                              |                                |         |      |          |                  |
| $I_H$          | holding current                                      | $V_D = 6\text{ V}$ $R_{GK} = \infty$                                                                                                                                                                  | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 70       | mA               |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$                                                                                                                                                                           | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 2        | $\mu\text{s}$    |
|                |                                                      | $I_G = 0,5\text{ A}; di_G/dt = 0,5\text{ A}/\mu\text{s}$                                                                                                                                              |                                |         |      |          |                  |
| $t_q$          | turn-off time                                        | $V_R = 100\text{ V}; I_T = 40\text{ A}; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^{\circ}\text{C}$<br>$di/dt = 10\text{ A}/\mu\text{s}; dv/dt = 20\text{ V}/\mu\text{s}; t_p = 200\text{ }\mu\text{s}$ |                                |         | 150  |          | $\mu\text{s}$    |

| Package TO-247 |                              |              | Ratings |      |      |      |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions   | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal |         |      | 70   | A    |
| $T_{VJ}$       | virtual junction temperature |              | -40     |      | 150  | °C   |
| $T_{op}$       | operation temperature        |              | -40     |      | 125  | °C   |
| $T_{stg}$      | storage temperature          |              | -40     |      | 150  | °C   |
| Weight         |                              |              |         | 6    |      | g    |
| $M_D$          | mounting torque              |              | 0,8     |      | 1,2  | Nm   |
| $F_C$          | mounting force with clip     |              | 20      |      | 120  | N    |

### Product Marking



### Part description

C = Thyristor (SCR)  
 M = Thyristor  
 A = (up to 1800V)  
 80 = Current Rating [A]  
 MT = 1~ Triac  
 1600 = Reverse Voltage [V]  
 N = Three Quadrants operation: QI - QIII  
 HB = TO-247AD (3)

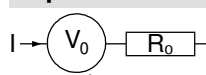
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | CMA80MT1600NHB  | CMA80MT1600NHB     | Tube          | 30       | 522868   |

| Similar Part   | Package    | Voltage class |
|----------------|------------|---------------|
| CMA80MT1600NHR | ISO247 (3) | 1600          |

### Equivalent Circuits for Simulation

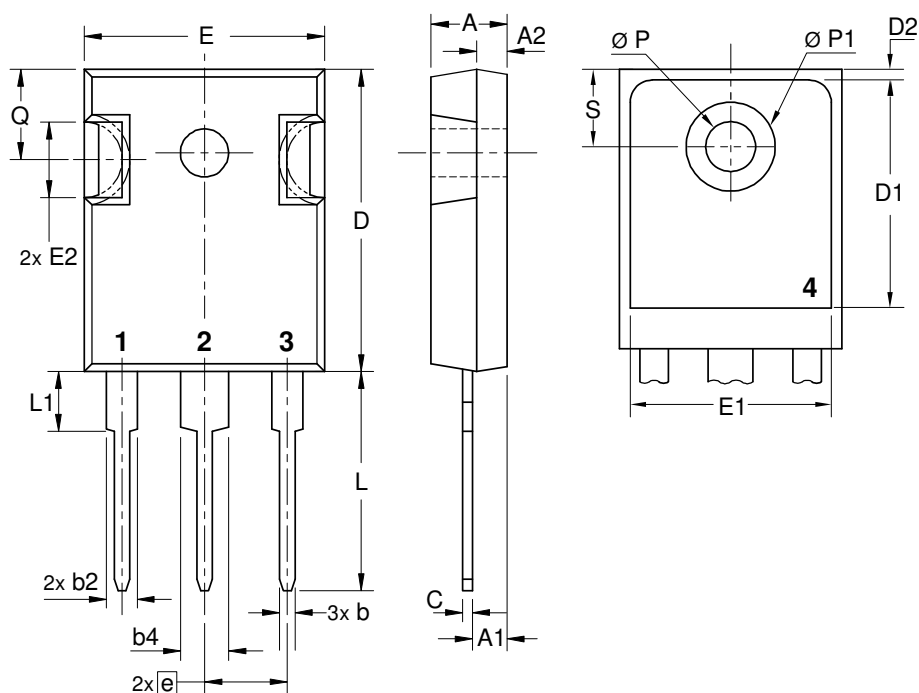
\* on die level

$T_{VJ} = 150^{\circ}\text{C}$

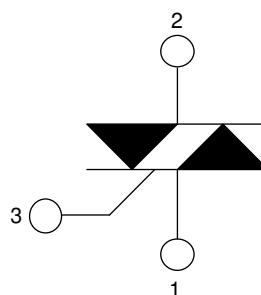


Thyristor

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0 \max}$ | threshold voltage  | 0,89 | V  |
| $R_{0 \max}$ | slope resistance * | 8,8  | mΩ |

**Outlines TO-247**


| Sym. | Inches |       | Millimeter |       |
|------|--------|-------|------------|-------|
|      | min.   | max.  | min.       | max.  |
| A    | 0.185  | 0.209 | 4.70       | 5.30  |
| A1   | 0.087  | 0.102 | 2.21       | 2.59  |
| A2   | 0.059  | 0.098 | 1.50       | 2.49  |
| D    | 0.819  | 0.845 | 20.79      | 21.45 |
| E    | 0.610  | 0.640 | 15.48      | 16.24 |
| E2   | 0.170  | 0.216 | 4.31       | 5.48  |
| e    | 0.215  | BSC   | 5.46       | BSC   |
| L    | 0.780  | 0.800 | 19.80      | 20.30 |
| L1   | -      | 0.177 | -          | 4.49  |
| Ø P  | 0.140  | 0.144 | 3.55       | 3.65  |
| Q    | 0.212  | 0.244 | 5.38       | 6.19  |
| S    | 0.242  | BSC   | 6.14       | BSC   |
| b    | 0.039  | 0.055 | 0.99       | 1.40  |
| b2   | 0.065  | 0.094 | 1.65       | 2.39  |
| b4   | 0.102  | 0.135 | 2.59       | 3.43  |
| c    | 0.015  | 0.035 | 0.38       | 0.89  |
| D1   | 0.515  | -     | 13.07      | -     |
| D2   | 0.020  | 0.053 | 0.51       | 1.35  |
| E1   | 0.530  | -     | 13.45      | -     |
| Ø P1 | -      | 0.29  | -          | 7.39  |



## Thyristor

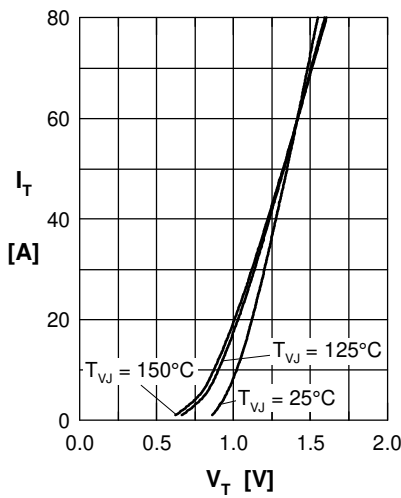


Fig. 1 Forward characteristics

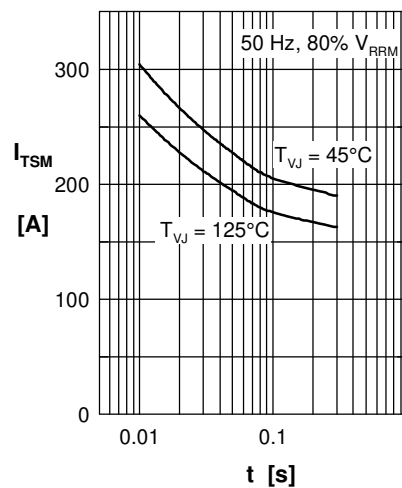


Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

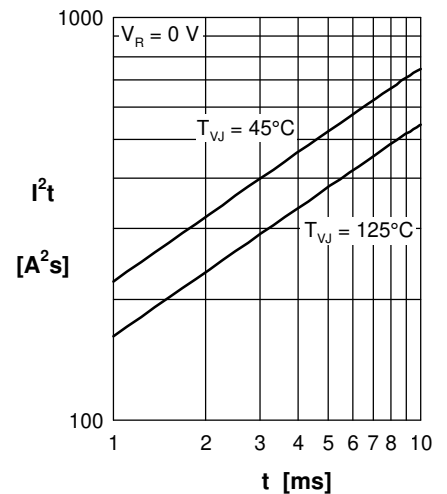


Fig. 3  $I^2t$  versus time (1-10 s)

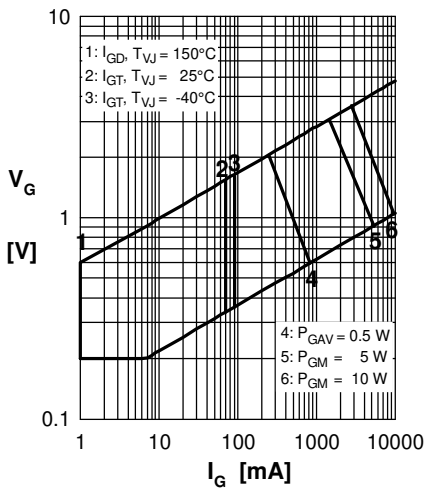


Fig. 4 Gate voltage & gate current

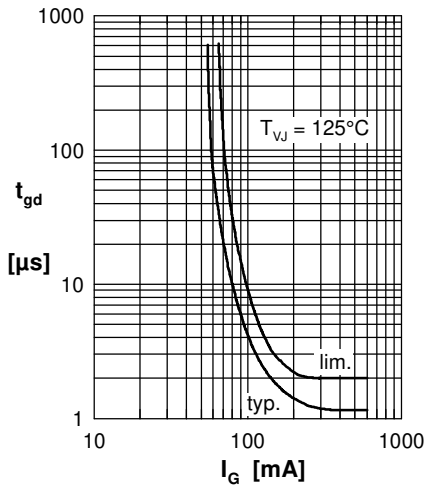


Fig. 5 Gate controlled delay time  $t_{gd}$

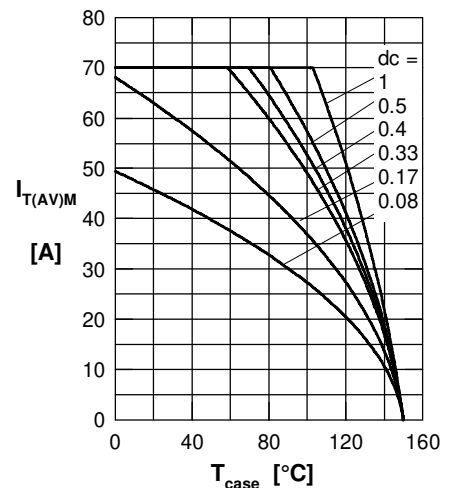


Fig. 6 Max. forward current at case temperature

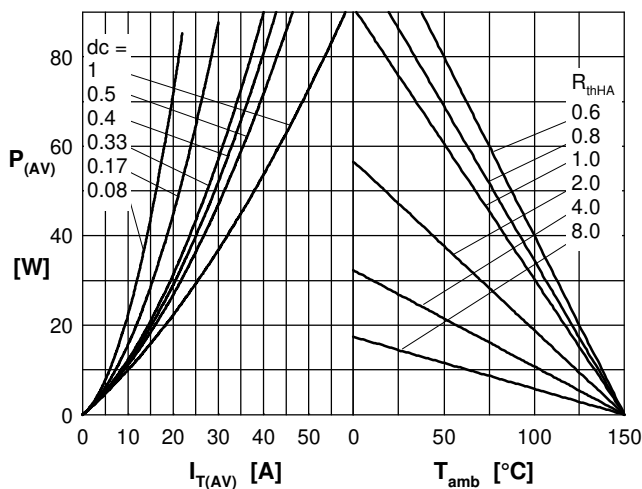


Fig. 7a Power dissipation versus direct output current  
 Fig. 7b and ambient temperature

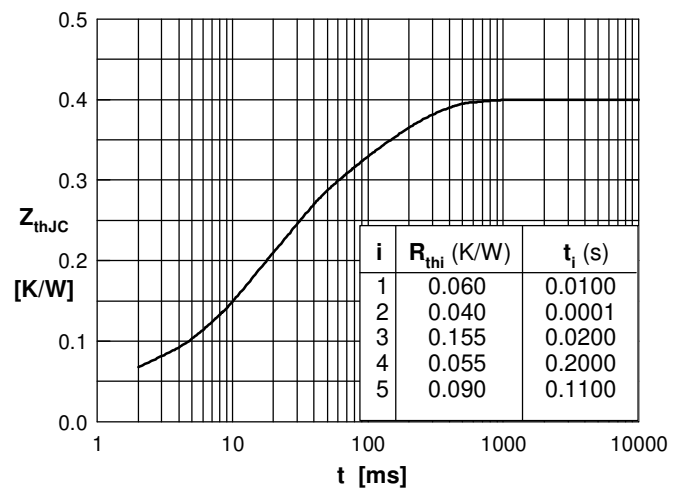


Fig. 8 Transient thermal impedance junction to case